

Switch disconnecter for galvanic direct current interruption

The invention relates to a disconnecting apparatus for direct current interruption between a direct current source and an electrical device,
5 having a current-conducting mechanical switching contact and semiconductor electronics connected in parallel therewith, according to the pre-characterizing clause of claim 1. Such a disconnecting apparatus is known, for example, from DE 10 2005 040 432 A1.

A direct current source is hereby understood in particular to be a
10 photovoltaic generator (solar installation) and an electrical device is understood in particular to be an inverter.

DE 20 2008 010 312 U1 discloses a photovoltaic installation or solar installation having a so-called photovoltaic generator which for its part consists of solar panels combined in groups to form partial generators,
15 connected in series or present in parallel rows. While a partial generator delivers its direct current output via two terminals, the direct current output of the whole photovoltaic generator is fed via an inverter into an alternating current voltage network. In order thereby to minimize the complexity of cabling and power losses between the partial generators and the central
20 inverter, so-called generator junction boxes are arranged close to the partial generators. The direct current output commutated in this way is normally conducted via a common cable to the central inverter.

As, depending on the system, a photovoltaic installation, on the one hand, permanently delivers an operating current and an operating voltage in the
25 range between 180V (DC) and 1500V (DC) and, on the other hand, for example for the purpose of installation, mounting or servicing and in particular generally to protect people too, a reliable disconnection is desired of the electrical components or devices from the photovoltaic installation which acts as a direct current source, a corresponding disconnecting
30 apparatus must be able to effect an interruption under load, i.e. without any prior switching off of the direct current source.

For load disconnection, a mechanical switch (switching contact) can be used which has the advantage that a galvanic disconnection of the electrical device (inverter) from the direct current source (photovoltaic installation) is produced when the contact has been opened. The

5 disadvantages, however, exist that such mechanical switching contacts become worn out very quickly because of the arc which occurs when the contact is opened, and that additional expense is required in order to enclose and cool down the arc, which is normally effected by a corresponding mechanical switch with an extinguishing chamber.

10 If, in contrast, powerful semiconductor switches are used for the load disconnection, unavoidable power losses at the semiconductors also occur in normal operation. In addition, no galvanic disconnection and hence no reliable protection for people is ensured with such power semiconductors.

DE 102 25 259 B3 discloses an electrical plug-in connector, designed as a
15 load disconnecter, which, in the manner of a hybrid switch, has a semiconductor switch element in the form, for example, of a thyristor in the housing of the inverter as well as main and auxiliary contacts which are connected to photovoltaic panels. The main contact, which is the leading one in the unplugging process, is connected in parallel with the trailing
20 auxiliary contact and the auxiliary contact connected in series with the semiconductor switch element. The semiconductor switch element is here controlled in order to prevent the occurrence of an arc or extinguish such an arc, by being periodically switched on and off.

DE 103 15 982 A2 discloses, for the interruption of direct current, a hybrid
25 electromagnetic direct current switch with an electromagnetically actuated main contact and an IGBT (insulated gate bipolar transistor) as the semiconductor switch.

However, known hybrid switches always have an external energy source for controlling the semiconductor switch and for operating semiconductor
30 electronics into which the semiconductor switch is inserted.

The object of the invention is to provide a particularly suitable disconnecting apparatus for direct current interruption between a direct current source, in particular a photovoltaic generator, and an electrical device, in particular an inverter.

- 5 This object is achieved according to the invention by the features of claim 1. For this purpose, the disconnecting switch suitably comprises a mechanical switching contact which is designed for an arc of short duration, i.e. for an arc duration of less than 1ms, preferably less than or equal to 500µs. The mechanical switching contact (switch or disconnecting element)
- 10 is connected in parallel with semiconductor electronics which comprise a first semiconductor switch, preferably an IGBT, and a secondary semiconductor switch, preferably a MOSFET.

- The semiconductor electronics of the disconnecting switch according to the invention have no additional energy source and consequently, when the
- 15 mechanical switch is closed, act as a current barrier, i.e. have a high impedance and are thus virtually current- and voltage-free. As, when the mechanical switching contacts are closed, no current flows across the semiconductor electronics and therefore there is no voltage drop in particular across the or each semiconductor switch, the semiconductor
- 20 circuit also causes no power losses when the mechanical switch is closed. Instead, the semiconductor electronics obtain the energy it needs for operation from the disconnecting apparatus, i.e. from the disconnecting switch system itself. The energy of the arc which occurs when the mechanical switch is opened is called on and used for this. A control input
- 25 for the semiconductor electronics or the semiconductor switch is hereby connected to the mechanical switching contacts in such a way that, when the switch opens, the arc voltage, across the switch or its switching contacts and the semiconductor electronics connected in parallel therewith, as a consequence of the arc makes the semiconductor electronics current-
- 30 conductive, i.e. with a low impedance and hence current-carrying.

As soon as the semiconductor electronics become even slightly current-conductive, the arc current begins to commutate from the mechanical switch to the semiconductor electronics. The corresponding arc voltage or the arc

current hereby charges an energy store preferably in the form of a condenser which discharges with the generation of a control voltage specifically in order to switch off the semiconductor electronics with no arc being formed. The preset duration or time constant and hence the charging duration of the energy store or condenser determines the duration of the arc.

Following the charging process, a timer preferably starts, during which the semiconductor electronics are controlled with no arc being formed and so as to create a current barrier. The duration of the timer is thus set so as to ensure safe extinguishing and reliable cooling of the arc or plasma.

The invention thus starts from the concept that a hybrid disconnecting apparatus designed as a pure two-terminal network can be used for shockproof and reliable direct current interruption, when semiconductor electronics can be used without their own source of auxiliary energy. This in turn can be achieved, as is recognized, by the arc energy that is generated when a mechanical switch connected in parallel with the electronics is opened being used for the operation of electronics. To do this, the electronics could have an energy store which stores at least part of the arc energy which is then made available to the electronics for a determined operating period which should be calibrated so as to ensure reliable extinguishing of the arc.

In a preferred embodiment, the condenser expediently provided as an energy store determines, in conjunction with an ohmic resistor, the charging duration or charging time constant of the energy store. The charging duration of the energy store and hence the arc duration is preferably set at less than 1ms, and expediently at less than or equal to 0.5ms. This duration is, on the one hand, short enough to reliably prevent undesired contact erosion of the switching contacts of the mechanical switch. On the other hand, this duration is long enough to ensure self-supply of the semiconductor electronics for the subsequent duration determined by the timer and within which the electronics are controlled from the low-impedance

commutating state into the high-impedance switched-off state (starting state). After the timer has elapsed, it is ensured that the extinguished arc cannot reoccur even with electronics connected with high impedance.

5 Reliable disconnection and direct current interruption are consequently obtained.

A further mechanical disconnecting switch is suitably provided as an additional safety element for a reliable galvanic interruption and disconnection and is connected in series with the parallel circuit consisting of the mechanical switch and the semiconductor electronics.

10 In a particularly preferred embodiment, the semiconductor electronics comprise, in addition to the power or semiconductor switch preferably designed as an IGBT, a further power or semiconductor switch which preferably takes the form of a MOSFET (metal oxide semiconductor field-effect transistor). The IGBT which can be controlled almost without any
15 power and displays good transmission characteristics at a high blocking voltage is thus connected suitably in series with the further semiconductor switch (MOSFET) in the manner of a cascode arrangement. The semiconductor switches thus form a commutation path parallel with the main current path formed by the mechanical switch and onto which the arc
20 current is increasingly commutated with the mechanical switch open and as a consequence of the or each semiconductor switch being turned on. The arc voltage which decreases during the commutation across the hybrid disconnecting switch and hence across the semiconductor electronics is between approximately 15V and 30V.

25 The first semiconductor switch (IGBT) is first turned on in such a way that sufficient voltage to charge the energy store, for example 12V (DC), can be tapped between the two semiconductor switches, in other words at a cascode center tap, as it were.

This voltage is used to charge the energy store and its stored energy is used in turn to control the semiconductor switches in the semiconductor electronics, so that the two semiconductor switches which are to be switched through can be completely switched off again, i.e. controlled so
5 that they act as a current barrier. The main path is then opened galvanically and the commutation path parallel thereto has a high impedance with the result that the high direct current voltage (permanently) generated by the direct current source appears at the hybrid disconnecting switch with, for example, more than 1000V (DC). It can therefore be ensured by the timer
10 that not only is the arc extinguished but the plasma thereby created is also cooled.

Complete galvanic direct current interruption is obtained by opening the mechanical disconnecting switch connected in series with this autarchic hybrid switch.

15 The advantages obtained with the invention consist in particular in that no external energy source or additional auxiliary energy is required to supply the electronics, owing to the use of an autarchic hybrid disconnecting apparatus in which the semiconductor electronics remove the energy needed for their own supply of voltage from the arc which occurs when the
20 mechanical switch is opened. The semiconductor electronics are preferably designed as a two-terminal network and have high impedance when the mechanical switch is closed, so that virtually no power losses occur at the hybrid disconnecting apparatus according to the invention during normal load operation.

25 The disconnecting apparatus according to the invention is preferably also suitably provided to interrupt direct current in the direct current voltage range up to 1500V (DC). In the preferred use of the additional mechanical disconnecting switch, this autarchic hybrid disconnecting apparatus is therefore particularly suited for reliable and shockproof galvanic direct
30 current interruption both between a photovoltaic installation and an inverter associated therewith and in conjunction with, for example, a fuel cell system or an accumulator (battery).

Exemplary embodiments of the invention are explained in more detail below with reference to the drawings, in which:

- Figure 1 shows, in a block circuit diagram, the disconnecting apparatus according to the invention with an autarchic hybrid disconnecting switch between a photovoltaic generator and an inverter,
- Figure 2 shows, in a comparatively more detailed circuit diagram, the disconnecting apparatus with two semiconductor switches in a cascode arrangement and with condensers as energy stores, and
- Figure 3 shows, in a graph plotting current/voltage against time, the resulting course of switch current and voltage over time before, during and after the extinguishing of an arc.

Mutually corresponding parts are provided in both Figures with the same reference symbols.

Figure 1 shows diagrammatically a disconnecting apparatus 1 which, in the exemplary embodiment, is connected between a photovoltaic generator 2 and an inverter 3. The photovoltaic generator 2 comprises a number of solar panels 4 which lie parallel with one another and are led to a common generator junction box 5 which serves, as it were, as an energy collection point.

The disconnecting apparatus 1 comprises, in the main current path 6 representing the positive terminal, a switching contact 7 which is also referred to below as a mechanical switch, and semiconductor electronics 8 connected in parallel therewith. The mechanical switch 7 and the semiconductor electronics 8 form an autarchic hybrid disconnecting switch. A further hybrid disconnecting switch 7, 8 can, in a manner not shown in more detail, be connected in the return line 9, representing the negative terminal, of the disconnecting apparatus 1, and hence the whole installation.

Mechanically coupled-together switching contacts of a further mechanical disconnecting element 10 can be arranged both in the outward line (main path) 6 representing the positive terminal and in the return line 9 for a

complete galvanic disconnection or direct current interruption between the photovoltaic generator 2 and the inverter 3.

The semiconductor electronics 8 essentially comprise a semiconductor switch 11 which is connected in parallel with the mechanical switch 7, and
 5 a control circuit 12 having an energy store 13 and a timer 14. The control circuit 12 is preferably connected to the main current path 6 via a resistor or a series of resistors R (Figure 2). The gate of an IGBT preferably inserted as a semiconductor switch 11 forms the control input 15 of the semiconductor circuit 8. This control input 15 is led to the main current path
 10 6 via the control circuit 12.

Figure 2 shows a comparatively more detailed circuit diagram of the electronics 8, connected in parallel with the mechanical switch 7, of the autarchic hybrid disconnecting switch. The first semiconductor switch (IGBT) 11a can be identified in a cascode arrangement connected in series
 15 with a second semiconductor switch 11b in the form of a MOSFET. The cascode arrangement with the two semiconductor switches 11a, 11b thus, analogously with Figure 1, forms the commutation path 16 parallel with the mechanical switch 7 and thus with the main current path 6.

In the disconnecting switch arrangement shown in Figure 1 and in the
 20 cascode arrangement illustrated in Figure 2, the first semiconductor switch 11a is led between the direct current source 2 and the hybrid disconnecting switch 7, 8 to the main current path 6. There the potential U_+ is always greater than the potential U_- on the opposite switch side at which the second semiconductor switch (MOSFET) 11b is guided to the main power
 25 circuit 6. The positive potential U_+ is 0V when the mechanical switch 7 is closed.

The first semiconductor switch (IGBT) 11a is connected to a freewheeling diode D2. A first Zener diode D3 is connected on the anode side to the potential U_- and on the cathode side to the gate (control input 15) of the first
 30 semiconductor switch (IGBT) 11a. A further Zener diode D4 is connected

on the cathode side in turn to the gate (control input 15) and on the anode side to the emitter of the first semiconductor switch (IGBT) 11a.

A diode D1 is led on the anode side to a center or cascode tap 17 between the first and second semiconductor switches 11a and 11b of the cascode arrangement, and is connected on the cathode side to the potential U. via a
 5 condenser C which serves as an energy store 13. The energy store 13 can also be formed by multiple condensers C. Via an anode-side voltage tap 18 between the diode D1 and the energy store 13 and the condenser C, a transistor T1 connected to ohmic resistors R1 and R2 is connected via
 10 further resistors R3 and R4 to the gate of the second semiconductor switch (MOSFET) 15, guided in turn to the control input 15 of the semiconductor electronics 8. A further Zener diode D5 with a parallel resistor R5 is connected on the cathode side to the gate and on the anode side to the emitter of the second semiconductor switch (MOSFET) 11b.

15 The transistor T1 is controlled on the base side by a transistor T2 which for its part is connected on the base side via an ohmic resistor R6 to the timer 14 which is designed, for example, as a monoflop. The transistor T2 is additionally connected on the base/emitter side to a further resistor R7.

Figure 3 shows, in a graph plotting current/voltage against time, the course
 20 of the switch voltage U and the switch current I of the hybrid disconnecting switch 7, 8 over time before a contact of the mechanical switch 7 opens at time t_K and during the duration t_{LB} of an arc LB across the switch 7 or its switching contacts 7a, 7b (Figure 2), as well as during a duration t_{ZG} specified, predetermined or set by the timer 14. When the mechanical
 25 switch 7 is closed, the main current path 6 has low impedance, whereas the parallel commutation path 16 of the hybrid disconnecting switch 7, 8 has high impedance and thus acts as a current barrier.

The current course illustrated in the left-hand side of Figure 3 represents the current I flowing exclusively across the mechanical switch 7 until the

time t_K of the contact opening of the switching contacts 7a and 7b. The opening of the mechanical switch 7 has already taken place at a time, not specified in more detail, before the time t_K of the contact opening. The switch voltage U illustrated in the left-hand lower half of Figure 3 is virtually 0V before the time t_K of the contact opening and increases steeply with the opening of the switching contacts 7a, 7b of the mechanical switch 7 at time t_K to a value which is characteristic for an arc LB and with a typical arc voltage U_{LB} of, for example, 20V to 30V. The positive potential U_+ thus tends towards this arc voltage $U_{LB} \approx 30V$ when the mechanical switch 7 opens.

During the duration (arc time interval) t_{LB} following the contact opening time t_K , the commutation begins of the switch current I , substantially corresponding to the arc current, from the main current path 6 onto the commutation path 16.

During the duration t_{LB} the arc current I is virtually split between the main current path 6 – in other words across the mechanical switch 7 – and the commutation path 16 – in other words, the semiconductor electronics 8. The energy store 13 is charged during this arc time interval t_{LB} . The duration t_{LB} is here set such that, on the one hand, sufficient energy is made available for reliable control of the semiconductor electronics 8, in particular to switch them off for a period t_{ZG} subsequent to the duration t_{LB} representing the duration of the arc. On the other hand, the duration t_{LB} is sufficiently short to prevent undesirable contact erosion or wear of the switch 7 or the switching contacts 7a, 7b.

When the arc LB begins and the arc voltage U_{LB} occurs, the first semiconductor switch (IGBT) 11a is turned on by the resistor R (Figure 2) at least to such an extent that a sufficient charging voltage and a sufficient arc or charging current is made available for the condensers C and hence for the energy store 13. To do this, a control circuit for the electronics 8 is preferably created with the corresponding connection of the first semiconductor switch (IGBT) 11a to the resistor R and the Zener diode $D3$,

via which control circuit the voltage is set at the cascode tap 17 to, for example, $U_{Ab} = 12V$ (DC). A fraction of the arc current and hence of the switch current I of the hybrid disconnecting switch 7, 8 hereby flows through the first semiconductor switch (IGBT) 11a close to the positive potential U_+ .

The tapping voltage U_{Ab} serves to supply the control circuit 12 of the electronics 8, formed essentially by the transistors T1 and T2 as well as the timer 14 and the energy store 13. The diode D1 which is connected on the anode side to the cascode tap 17 and on the cathode side to the condenser C prevents the charging current from flowing back from the condensers C and via the commutation path 16 toward the potential U_- .

If sufficient energy is contained in the condenser C and hence in the energy store 13, and consequently if a sufficiently high control or switching voltage U_{Sp} is present at the voltage tap 18, the transistor T1 and consequently the transistor T2 turn on, so that the two semiconductor switches 11a, 11b also turn on completely. Because the resistance of the now turned-on semiconductor switches 11a, 11b is substantially lower than the very high resistance of the gap section, formed by the open switch 7, of the main current path 6, the arc or switch current I flows almost exclusively via the commutation path 16. The positive potential U_+ thus again tends toward 0V when the switch current I is commutated onto the electronics 8. The arc LB is consequently extinguished between the contacts 7a, 7b of the mechanical switch 7.

The charging capacity and hence the stored energy contained in the condenser C is calculated such that the semiconductor electronics 8 carries the switch current I for a duration t_{ZG} predetermined by the timer 14. This duration t_{ZG} can be set to, for example, $t_{ZG} = 3ms$. This duration t_{ZG} is calculated, and the timer 14 is thus set, essentially in accordance with the application-specific or typical durations for complete extinguishing of the arc LB and with sufficient cooling of the plasma formed thereby. A decisive

factor hereby is that no new arc LB can occur after the electronics 8 have been switched off, with a commutation path 16 which as a result in turn has high impedance and semiconductor electronics 8 that consequently act as a current barrier at the still open mechanical switch 7 or over its switching contacts 7a, 7b.

At the end of the duration t_{ZG} set by the timer 14, the switch current I falls to almost zero ($I = 0A$), while at the same time the switch voltage increases to the operating voltage U_B delivered by the direct current source 2, for example by 1000V (DC) to 1500V (DC). The positive potential U_+ thus tends toward this operating voltage $U_B \approx 1000V$ when the commutation path 16 has high impedance owing to the blocking of the semiconductor switches 11 and the electronics 8 hence again act as a current barrier.

As at this time the main current path 6 is galvanically open, with the commutation path 16 simultaneously having high impedance, arc-less direct current interruption between the direct current source 2 and the electrical device 3 is already achieved. The connection between the direct current source 2 and the inverter 3 which, for example, takes the form of the electrical device is consequently already reliably broken. To effect a shockproof galvanic interruption, the mechanical disconnecting element 10 of the disconnecting apparatus 1 can then additionally be opened with no load or arc.

List of reference symbols

	1	Disconnecting apparatus
	2	Direct current source
5	3	Inverter
	4	Solar panel
	5	Generator junction box
	6	Main current path
	7	Switching contact/switch
10	7a, 7b	Contact
	8	Semiconductor electronics
	9	Return line
	10	Disconnecting element
	11a	First semiconductor switch
15	11b	Second semiconductor switch
	12	Control circuit
	13	Energy store
	14	Timer
	15	Control input
20	16	Commutation path
	17	Cascode/Center tap
	18	Voltage tap
	I	Switch current
25	t_K	Contact opening time
	t_{LB}	Arc duration
	t_{ZG}	Duration of the timer
	U	Switch voltage
	U_B	Operating voltage
30	U_{LB}	Arc voltage

Claims

1. A disconnecting apparatus (1) for direct current interruption between a
5 direct current source (2) and an electrical device (3), in particular
between a photovoltaic generator and an inverter, having a current-
conducting mechanical switching contact (7) and semi-conductor
electronics (8) connected in parallel therewith and which acts as a
current barrier when the switching contact (7) is closed, wherein when
10 the semiconductor electronics (8) become current-conductive, the arc
current (I_B) is commutated from the switching contact (7) to the
semiconductor electronics (8) characterized in that:
- the semiconductor electronics (8) have a first semiconductor
15 switch (11a) and a second semiconductor switch (11b)
connected in series thereto,
 - a control input (15) for the semiconductor electronics (8) is
connected to the switching contact (7) in such a way that, when
the switching contact opens, an arc voltage (U_B) generated
20 across the switching contact (7) as a consequence of an arc (I_B)
makes the semiconductor electronics (8) current-conductive,
wherein the semiconductor electronics (8) have an energy store
(13) which charges itself as a consequence of the arc (I_B) within
the arc duration (t_B), and
 - at the end of the charging time (t_B) of the energy store (13), a
25 timer (14) starts in order to switch off the semiconductor
electronics (8) with no arc being formed.
2. The disconnecting apparatus (1) as claimed in claim 1, characterized
in that at the end of the charging time (t_B) of the energy store (13),
30 the switch current (I) which flows as a result of the arc (I_B) is
completely commutated to the semiconductor electronics (8).

3. The disconnecting apparatus (1) as claimed in claim 1 or 2,
characterized in that the arc duration (t_{LB}) is determined by the
charging duration or capacity of the energy store (13).
- 5 4. The disconnecting apparatus (1) as claimed in one of claims 1 to 3,
characterized in that the semiconductor electronics (8) have an IGBT
and a MOSFET connected in series thereto.
- 10 5. The disconnecting apparatus (1) as claimed in one of claims 1 to 4,
characterized in that the arc voltage (U_{LB}) is tapped between the first
semiconductor switch (11a) and the second semiconductor switch
(11b) in order to charge the energy store (13).
- 15 6. The disconnecting apparatus (1) as claimed in one of claims 1 to 5,
characterized in that the (first) semiconductor switch (11a) has a
control input which is guided via an ohmic resistor (R) to the positive
voltage potential of the direct current source (2) when the switching
contact (7) is open.
- 20 7. The disconnecting apparatus (1) as claimed in one of claims 1 to 6,
characterized by a mechanical disconnecting element (10) for
galvanic direct current interruption, connected in series with the
parallel circuit consisting of the mechanical switching contact (7) and
the semiconductor electronics (8).